



Bipolar NPN Bare Die – BTN6988

Part Description

The BTN6988 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = 50V
- VCEO = 25V
- VEBO = 7V
- hFE = 250-550 @ VCE = 2V, IC = 0.5A
- VCE(Sat) = 0.5V @ IC = 4A, IB = 200mA
- fT = 400 MHz @ VCE = 10V, IE = 0A
- COBO = 15pF @ VCB = 10V

Features

Low VCE(sat)

Die Size (Unawn)

940µm X 940µm, 37 Mils X 37 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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